

DRD7810H34

Rectifier Diode

DS6015-2 December 2011 (LN28901)

Replaces DS6015-1

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

 $\begin{array}{ll} V_{RRM} & 3400V \\ I_{F(AV)} & 7810A \\ I_{FSM} & 118000A \end{array}$

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD7810H34 DRD7810H32 DRD7810H30 DRD7810H28 DRD7810H26 DRD7810H24	3400 3200 3000 2800 2600 2400	$V_{RSM} = V_{RRM} + 100V$

Outline type code: H (See Package Details for further information)

Fig. 1 Package outline

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD7810H34 for a 3400V device

CURRENT RATINGS

T_{case} = 75°C unless stated otherwise

Symbol	Parameter	Test Conditions		Units			
Double Si	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load	9740	Α			
I _{F(RMS)}	RMS value	-	15290	Α			
I _F	Continuous (direct) on-state current	-	13770	Α			

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units			
Double Si	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load	7810	Α			
I _{F(RMS)}	RMS value	-	12260	Α			
I _F	Continuous (direct) on-state current	-	11040	А			

SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 160°C	118.0	kA
l ² t	I ² t for fusing	$V_R = 0$	69.62	MA ² s

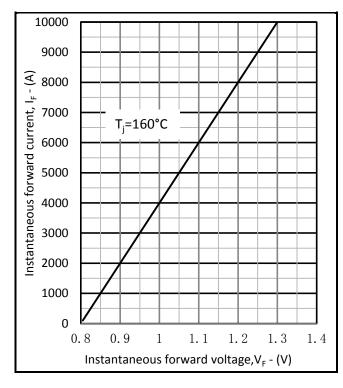
THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	5	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance – junction to case	Double side cooled	DC	-	0.004	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Double side cooled	DC	-	0.0008	°C/W
T _{vj}	Virtual junction temperature	Blocking V _{DRM} / _{VRRM}		-40	160	°C
T _{stg}	Storage temperature range			-40	160	°C
F _m	Clamping force			110	130	kN

CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 6000A peak, T _{case} = 160°C	-	1.10	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 160°C	-	600	mA
Q _S	Total stored charge	$I_F = 4000A$, $dI_{RR}/dt = 10A/\mu s$ $T_{case} = 160$ °C, $V_R = 100$ V	-	8000	μC
V _{TO}	Threshold voltage	At T _{vj} = 160°C	-	0.80	V
r _T	Slope resistance	At T _{vj} = 160°C	-	0.05	mΩ

CURVES



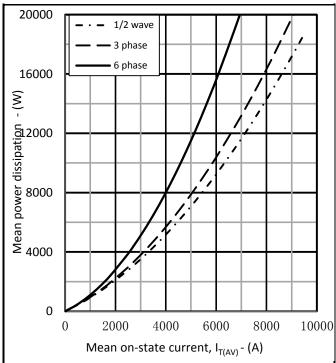
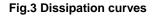


Fig.2 Maximum forward characteristics



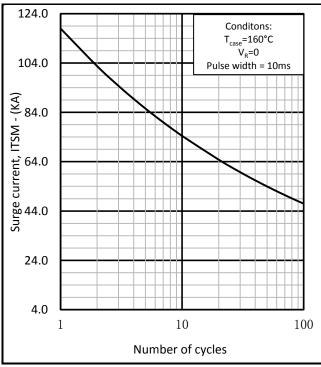


Fig.4 Surge (Non-Repetitive) Forward current vs time

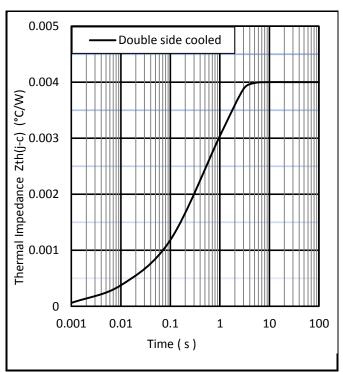
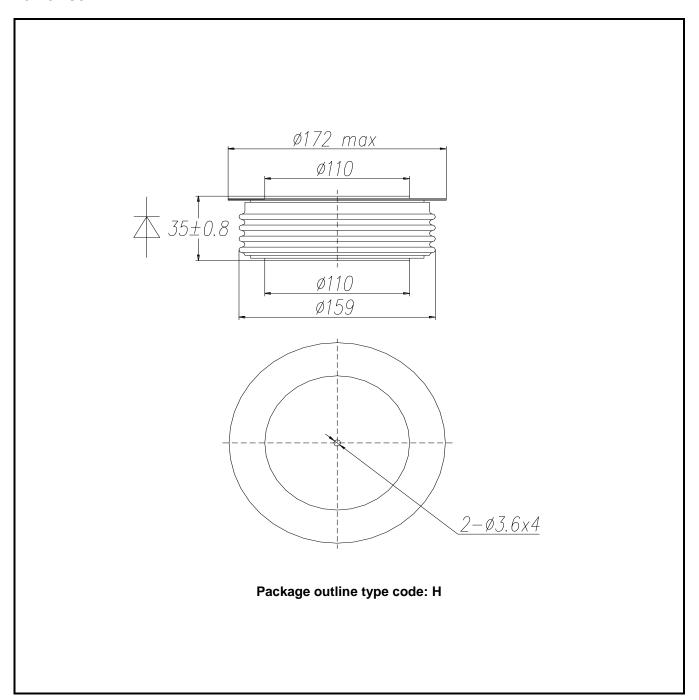


Fig.5 Maximum (limit) transient thermal impedancejunction to case

PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

Some packages may be supplied with gate and or tags.

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